NSN 5962-01-050-5900

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View Online at https://aerobasegroup.com/nsn/5962-01-050-5900

Body Length:

Between 1.190 inches and 1.230 inches

Body Width:

Between 0.580 inches and 0.610 inches

Body Height:

Between 0.080 inches and 0.120 inches

Maximum Power Dissipation Rating:

675.0 milliwatts

Operating Tempurature Range:

+0.0/+75.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and monolithic and positive outputs and schottky and high speed and w/enable and w/storage and w/strobe and

w/disable and 3-state output and programmable and programmed and w/decoded output

Inclosure Material:

Ceramic and metal

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

12 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-1.5 volts power source and 5.5 volts power source

Time Rating Per Chacteristic:

35.00 nanoseconds propagation delay time, low to high level output and 45.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Prom

Memory Capacity:

Unknown

Test Data Document:

08783-37654883 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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- Demilitarization:

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